
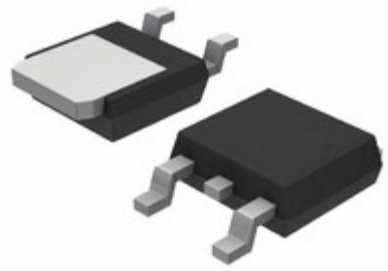
	<h2 style="color: #E67E22;">NTD20N06LG</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">NTD20N06LG</a></p> <hr/> <p><b>Hersteller / Marke:</b> <a href="#">AMI Semiconductor / ON Semiconductor</a></p> <hr/> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 60V 20A DPAK</p> <hr/> <p><b>Datenblätter:</b>  <a href="#">NTD20N06LG.pdf</a></p> <hr/> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <hr/> <p><b>Lagerzustand:</b> New original, 5010 pcs Stock Available.</p> <hr/> <p><b>Liefern von:</b> Hong Kong</p> <hr/> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">NTD20N06LG</a>
Hersteller	<a href="#">AMI Semiconductor / ON Semiconductor</a>
Beschreibung	MOSFET N-CH 60V 20A DPAK
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	5010 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (Tj)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	DPAK
Verlustleistung (max)	1.36W (Ta), 60W (Tj)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	20A (Ta)
Rds On (Max) @ Id, Vgs	48 mOhm @ 10A, 5V
VGS (th) (Max) @ Id	2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	32nC @ 5V
Eingabekapazität (Ciss) (Max) @ Vds	990pF @ 25V
Verpackung	Tube

NTD20N06LG ist neu im Original, Suche NTD20N06LG Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTD20N06LG AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTD20N06LG: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>NTD20N06T4G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 20A DPAK</p>	 <p><b>NTD20N06HL</b> O NTD20N06HL O</p>	 <p><b>NTD20N06T4</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 20A DPAK</p>	 <p><b>NTD20N06HDLT4G</b> ON NTD20N06HDLT4G ON</p>
 <p><b>NTD20N06LT4</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 20A DPAK</p>	 <p><b>NTD20N06V</b> ON NTD20N06V ON</p>	 <p><b>NTD20N06LT4G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 20A DPAK</p>	 <p><b>NTD20N06L-1G</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 20A IPAK</p>

### heiße Teile

Mehr

NTD18N06-1G	NTD18N06G	NTD18N06L	NTD18N06L-1G	NTD18N06LG
NTD18N06LT4G	NTD18N06T4G	NTD20N03	NTD20N03G	NTD20N03HL
NTD20N03L27	NTD20N03L27G	NTD20N03L27T	NTD20N03L27T4	NTD20N03L27T4G
NTD20N03RT4G	NTD20N06	NTD20N06-001	NTD20N06-1G	NTD20N06HD
NTD20N06HDLT4G	NTD20N06HL	NTD20N06L	NTD20N06L-001	NTD20N06L-1G
NTD20N06LT4	NTD20N06LT4G	NTD20N06T4G	NTD20N06V	NTD20P03
NTD20P03HDLT4G	NTD20P06HCT4G	NTD20P06HD	NTD20P06HDLT4	NTD20P06HL
NTD20P06L	NTD20P06L-001	NTD20P06LG	NTD20P06LT4G	NTD23N03R-1
NTD23N03R-1G	NTD23N03RG	NTD23N03RT4	NTD23N03RT4G	NTD24N06
NTD24N06-1G	NTD24N06G	NTD24N06L	NTD24N06L-001	NTD24N06L-1G

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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